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Rohm Semiconductor RTE002P02TL

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Datasheet of RTE002P02TL - MOSFET P-CH 20V 0.2A SOT416
Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

RTE002P02

Transistors

2.5V Drive Pch MOS FET RTE002P02

Structure

Silicon P-channel MOS FET

Features

- 1) Low On-resistance.
- 2) Small package (EMT3).
- 3) 2.5V drive.

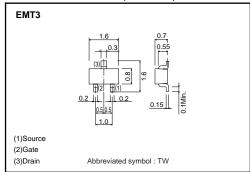
Applications

Switching

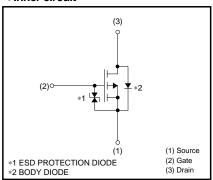
Package specifications

	Package	Taping	
Туре	Code	TL	
	Basic ordering unit (pieces)	3000	
RTE002P02	0		

External dimensions (Unit : mm)



•Inner circuit



● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit		
Drain-source voltage		V _{DSS}	-20	V		
Gate-source voltage		V_{GSS}	±12	V		
Danie august	Continuous	ID	±0.2	A		
Drain current	Pulsed	I _{DP} *1	±0.4	Α		
Total power dissipation		P _D *2	0.15	W		
Channel temperature		Tch	150	°C		
Range of storage temperature		Tstg	-55 to +150	°C		

^{*1} Pw≤10μs, Duty cycle≤1%

Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	Rth(ch-a)*	833	°C/W

^{*} Each terminal mounted on a recommended land



^{*2} Each terminal mounted on a recommended land





RTE002P02

Transistors

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	I _{GSS}	_	-	±10	μΑ	V _{GS} = ±12V, V _{DS} =0V
Drain-source breakdown voltage	V _(BR) DSS	-20	-	_	V	I _D = -1mA, V _G S=0V
Zero gate voltage drain current	IDSS	_	-	-1	μΑ	V _{DS} = -20V, V _{GS} =0V
Gate threshold voltage	VGS (th)	-0.7	-	-2.0	٧	V _{DS} = -10V, I _D = -1mA
Static drain-source on-state resistance	R _{DS} (on)*	-	1.0	1.5	Ω	I _D = -0.2A, V _G S= -4.5V
		-	1.1	1.6	Ω	I _D = -0.2A, V _G S= -4V
		-	2.0	3.0	Ω	I _D = -0.15A, V _G s= -2.5V
Forward transfer admittance	Y _{fs} *	0.2	-	-	S	V _{DS} = -10V, I _D = -0.15A
Input capacitance	Ciss	_	50	_	pF	V _{DS} = -10V
Output capacitance	Coss	-	5	_	pF	V _{GS} = 0V
Reverse transfer capacitance	Crss	-	5	_	pF	f=1MHz
Turn-on delay time	t _{d (on)} *	-	9	_	ns	V _{DD} ≒ –15V
Rise time	tr *	_	6	-	ns	ID= -0.15A
Turn-off delay time	t _{d (off)} *	_	35	_	ns	V _{GS} = -4.5V R _L = 100Ω
Fall time	t _f *	_	45	_	ns	R _G = 10Ω

*Pulsed

●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	Vsp	-	-	-1.2	V	I _S = -0.1A, V _{GS} =0V



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Appendix

Notes

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